

N-Channel 30-V (D-S) MOSFET

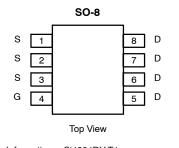
| PRODUCT SUMMARY | | | | | |
|---------------------|---------------------------------|--------------------|--|--|--|
| V _{DS} (V) | r _{DS(on)} (Ω) | I _D (A) | | | |
| 30 | 0.012 @ V _{GS} = 10 V | 12.5 | | | |
| | 0.018 @ V _{GS} = 4.5 V | 10.2 | | | |

FEATURES

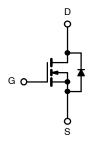
- TrenchFET® Power MOSFET
- Lead (Pb)-Free Version is RoHS Compliant



Pb-free Available



Ordering Information: Si4894DY-T1 Si4894DY-T1—E3 (Lead (Pb)-Free)



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED) | | | | | | | | |
|---|---------------------|-----------------------------------|------------|--------------|------|--|--|--|
| Parameter | | Symbol | 10 secs | Steady State | Unit | | | |
| Drain-Source Voltage | | V _{DS} | 30 | | V | | | |
| Gate-Source Voltage | | V _{GS} | ± 20 | | | | | |
| | $T_A = 25^{\circ}C$ | I _D | 12.5 | 8.5 | A | | | |
| Continuous Drain Current $(T_J = 150^{\circ}C)^a$ | $T_A = 70^{\circ}C$ | | 10 | 6.8 | | | | |
| Pulsed Drain Current | | I _{DM} | 20 | | | | | |
| Continuous Source Current (Diode Conduction) ^a | | I _S | 2.7 | 1.3 | А | | | |
| | $T_A = 25^{\circ}C$ | PD | 3.0 | 1.4 | w | | | |
| Maximum Power Dissipation ^a | $T_A = 70^{\circ}C$ | | 1.9 | 0.9 | | | | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to 150 | | °C | | | |

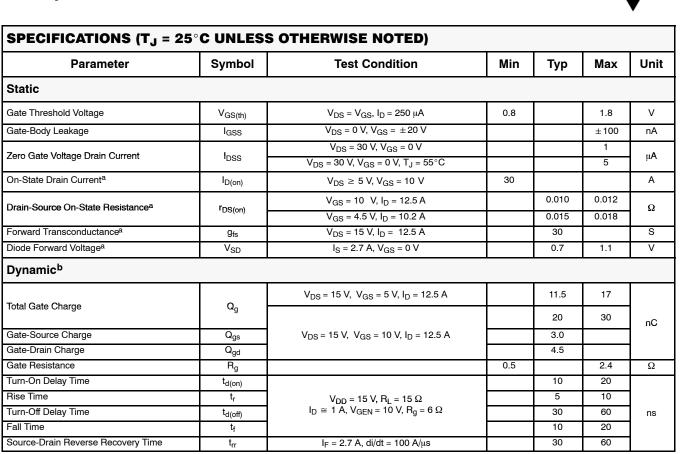
| THERMAL RESISTANCE RATINGS | | | | | | | | |
|--|------------------------|-------------------|---------|---------|------|--|--|--|
| Parameter | | Symbol | Typical | Maximum | Unit | | | |
| | $t \le 10 \text{ sec}$ | R _{thJA} | 35 | 42 | °C/W | | | |
| Maximum Junction-to-Ambient ^a | Steady State | | 73 | 90 | | | | |
| Maximum Junction-to-Foot (Drain) | Steady State | | 16 | 20 | | | | |

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

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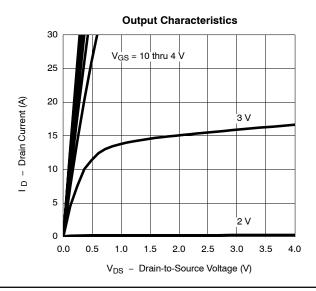
Notes

a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%.

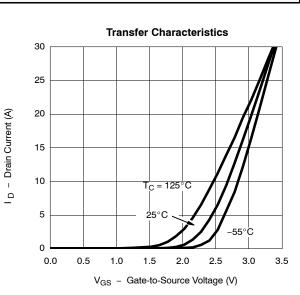
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



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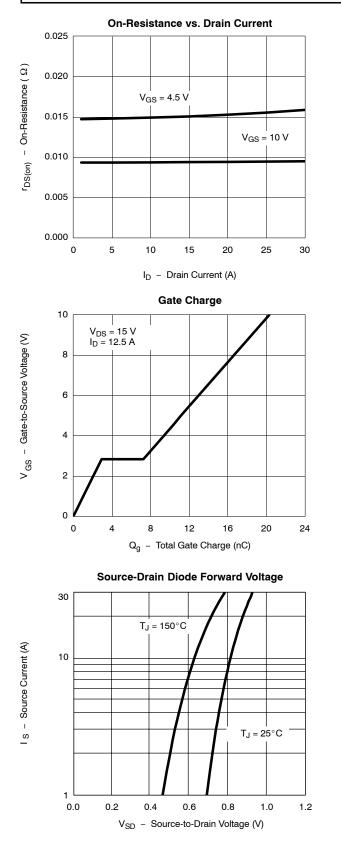


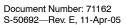
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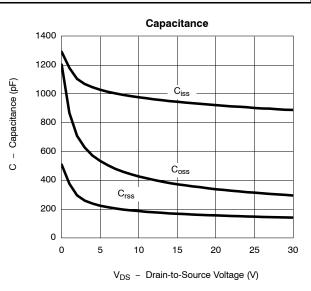


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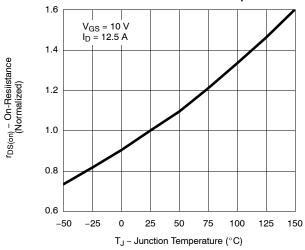
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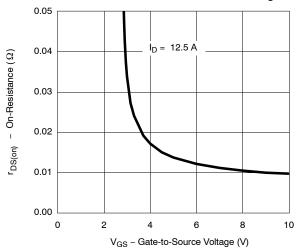




On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage

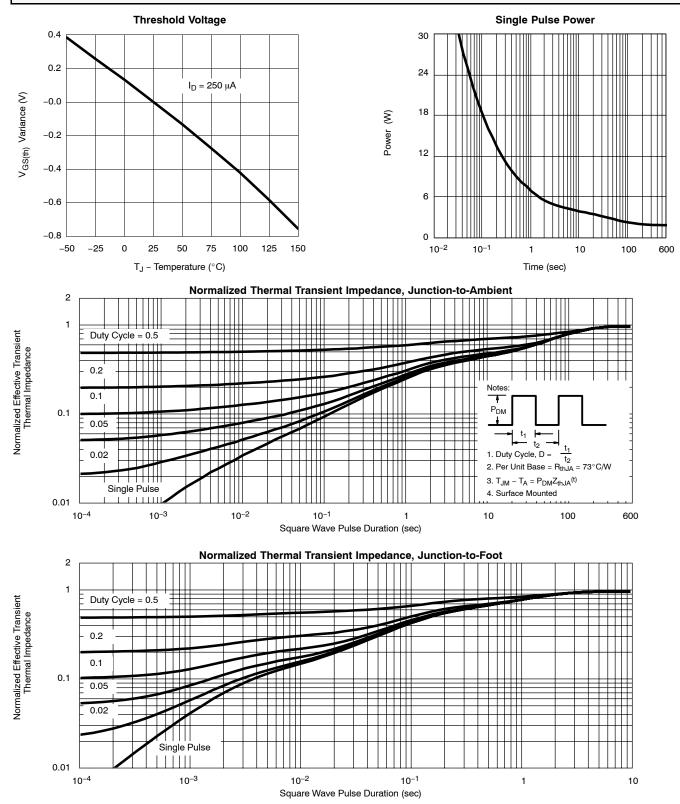


Si4894DY

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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71162.

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